



(11) **EP 1 852 480 B8**

(12) **CORRECTED EUROPEAN PATENT SPECIFICATION**

(15) Correction information:
Corrected version no 1 (W1 B1)
Corrections, see
Bibliography INID code(s) 73

(51) Int Cl.:
H01L 21/02 ^(2006.01) **C09G 1/02** ^(2006.01)
H01L 21/321 ^(2006.01) **C30B 33/00** ^(2006.01)
C30B 29/40 ^(2006.01)

(48) Corrigendum issued on:
12.12.2012 Bulletin 2012/50

(45) Date of publication and mention
of the grant of the patent:
26.09.2012 Bulletin 2012/39

(21) Application number: **07007629.4**

(22) Date of filing: **13.04.2007**

(54) **Method of processing a surface of group III nitride crystal and group III nitride crystal substrate**

Verfahren zum Bearbeiten einer Oberfläche aus Gruppe-III-Nitrid-Kristall und Gruppe-III-Nitrid-Kristallsubstrat

Procédé pour le traitement d'une surface de cristal de nitrure du groupe III et substrat de cristal de nitrure du groupe III

(84) Designated Contracting States:
DE FR GB

(30) Priority: **01.05.2006 JP 2006127443**

(43) Date of publication of application:
07.11.2007 Bulletin 2007/45

(73) Proprietor: **Sumitomo Electric Industries, Ltd.**
Osaka 541 0041 (JP)

(72) Inventors:
• **Nishiura, Takayuki**
Itami-shi
Hyogo 664-0016 (JP)

• **Ishibashi, Keiji**
Itami-shi
Hyogo 664-0016 (JP)

(74) Representative: **Grünecker, Kinkeldey,**
Stockmair & Schwanhäusser
Leopoldstrasse 4
80802 München (DE)

(56) References cited:
EP-A- 1 717 286 US-B1- 6 488 767

EP 1 852 480 B8

Note: Within nine months of the publication of the mention of the grant of the European patent in the European Patent Bulletin, any person may give notice to the European Patent Office of opposition to that patent, in accordance with the Implementing Regulations. Notice of opposition shall not be deemed to have been filed until the opposition fee has been paid. (Art. 99(1) European Patent Convention).